

Jan. 2023

BCH-260

1. Color Infrared

2. Material AlGaAs/GaAs

3. Electrode N side (cathode): Au / P side (anode): Au

4. Electrode pattern

5. Chip size 0.235mm × 0.235mm × 0.240mmH (Fig.)

6. Electro-Optical characteristics (Ta = 25°C)

Parameters	Symbol	Condition	Characteristics			Unit
			Min.	Тур.	Max.	Unit
Power*	Po	IF = 20mA	1.0	1.3		mW
Forward Voltage	VF	IF = 20mA		1.70	2.10	V
Reverse Current	lr	VR = 5V			10	μA
Peak Wavelength	λР	IF = 20mA		730		nm
Spectral Radiation Bandwidth	Δλ	IF = 20mA		25		nm
Rise time	tr	IF = 20mA	·	30		ns
Fall time	tf	IF = 20mA		20		ns

Power Measurement at RESONAC PHOTONICS.

LED chip: To be mounted on TO-18 gold header without resin coating.

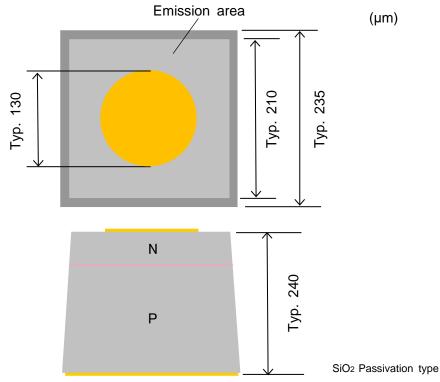


Fig. Electrode pattern & Chip size

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